



ISSUE CLAS:
Class

U.S. UTILITY Patent Application

MR SCANNED 6/4/11 Q.A. <i>[Signature]</i>	O.I.P.E. SBC <i>[Signature]</i>	PATENT DATE
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APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/885744		438		2812 22	K. nguyen

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Method for annealing ultra-thin, high quality gate oxide layers using oxidizer/hydrogen mixtures

11

PTO-2040
12/99

ISSUING CLASSIFICATION

TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.				NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____ _____ _____				ISSUE FEE	
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed				Amount Due	Date Paid
				ISSUE BATCH NUMBER	

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